

CPC COOPERATIVE PATENT CLASSIFICATION

H ELECTRICITY

(NOTE omitted)

H01 BASIC ELECTRIC ELEMENTS

(NOTE omitted)

H01C RESISTORS

NOTES

1. In this subclass, the term "adjustable" means mechanically adjustable.
2. Variable resistors, the value of which is changed non-mechanically, e.g. by voltage or temperature, are classified in group [H01C 7/00](#).

1/00	Details	1/1406	. . {Terminals or electrodes formed on resistive elements having positive temperature coefficient}
1/01	. Mounting; Supporting	1/1413	. . {Terminals or electrodes formed on resistive elements having negative temperature coefficient}
1/012	. . the base extending along and imparting rigidity or reinforcement to the resistive element (H01C 1/016 takes precedence; the resistive element being formed in two or more coils or loops as a spiral, helical or toroidal winding H01C 3/18 , H01C 3/20 ; the resistive element being formed as one or more layers or coatings on a base H01C 7/00)	1/142	. . the terminals or tapping points being coated on the resistive element
1/014	. . the resistor being suspended between and being supported by two supporting sections (H01C 1/016 takes precedence)	1/144	. . the terminals or tapping points being welded or soldered
1/016	. . with compensation for resistor expansion or contraction	1/146	. . the resistive element surrounding the terminal
1/02	. Housing; Enclosing; Embedding; Filling the housing or enclosure	1/148	. . the terminals embracing or surrounding the resistive element (H01C 1/142 takes precedence)
1/022	. . the housing or enclosure being openable or separable from the resistive element	1/16	. Resistor networks not otherwise provided for
1/024	. . the housing or enclosure being hermetically sealed (H01C 1/028 , H01C 1/032 , H01C 1/034 take precedence)	3/00	Non-adjustable metal resistors made of wire or ribbon, e.g. coiled, woven or formed as grids
1/026	. . . with gaseous or vacuum spacing between the resistive element and the housing or casing	3/005	. {Metallic glasses therefor}
1/028	. . the resistive element being embedded in insulation with outer enclosing sheath	3/02	. arranged or constructed for reducing self-induction, capacitance or variation with frequency
1/03	. . . with powdered insulation	3/04	. Iron-filament ballast resistors; Other resistors having variable temperature coefficient
1/032	. . plural layers surrounding the resistive element (H01C 1/028 takes precedence)	3/06	. Flexible or folding resistors, whereby such a resistor can be looped or collapsed upon itself
1/034	. . the housing or enclosure being formed as coating or mould without outer sheath (H01C 1/032 takes precedence)	3/08	. Dimension or characteristic of resistive element changing gradually or in discrete steps from one terminal to another
1/036	. . . on wound resistive element	3/10	. the resistive element having zig-zag or sinusoidal configuration
1/04	. Arrangements of distinguishing marks, e.g. colour coding	3/12	. . lying in one plane
1/06	. Electrostatic or electromagnetic shielding arrangements	3/14	. the resistive element being formed in two or more coils or loops continuously wound as a spiral, helical or toroidal winding (H01C 3/02 - H01C 3/12 take precedence)
1/08	. Cooling, heating or ventilating arrangements	3/16	. . including two or more distinct wound elements or two or more winding patterns
1/082	. . using forced fluid flow	3/18	. . wound on a flat or ribbon base (H01C 3/16 takes precedence)
1/084	. . using self-cooling, e.g. fins, heat sinks	3/20	. . wound on cylindrical or prismatic base (H01C 3/16 takes precedence)
1/12	. Arrangements of current collectors		
1/125	. . of fluid contacts		
1/14	. Terminals or tapping points {or electrodes} specially adapted for resistors (in general H01R); Arrangements of terminals or tapping points {or electrodes} on resistors		

7/00	Non-adjustable resistors formed as one or more layers or coatings; Non-adjustable resistors made from powdered conducting material or powdered semi-conducting material with or without insulating material (consisting of loose powdered or granular material H01C 8/00 ; {measuring deformation in a solid state using the change in resistance formed by printed-circuit technique G01B 7/20 ; insulating materials H01B 3/00 ; passive thin-film or thick-film semiconductor or solid state devices H01L 27/00 ; resistors without a potential-jump or surface barrier specially adapted for integrated circuits, details thereof, multistep manufacturing processes therefor H01L 28/20 }; resistors with a potential-jump barrier or surface barrier, e.g. field effect resistors H01L 29/00 ; semiconductor devices sensitive to electromagnetic or corpuscular radiation, e.g. photoresistors, H01L 31/00 ; devices using superconductivity H01L 39/00 ; devices using galvanomagnetic or similar magnetic effects, e.g. magnetic-field-controlled resistors, H01L 43/00 ; solid state devices for rectifying, amplifying, oscillating or switching without a potential-jump barrier or surface barrier H01L 45/00 ; bulk negative resistance effect devices H01L 47/00 ; {ohmic resistance heating H05B 3/00 ; printed circuits H05K })	7/047 {Vanadium oxides or oxidic compounds, e.g. VO _x }
		7/048	. . . {Carbon or carbides}
		7/049	. . {mainly consisting of organic or organo-metal substances (H01C 7/041 takes precedence)}
		7/06	. including means to minimise changes in resistance with changes in temperature
		7/10	. voltage responsive, i.e. varistors
		7/1006	. . {Thick film varistors}
		7/1013	. . {Thin film varistors}
		7/102	. . Varistor boundary, e.g. surface layers (H01C 7/12 takes precedence)
		7/105	. . Varistor cores (H01C 7/12 takes precedence)
		7/108	. . . Metal oxide
		7/112 ZnO type
		7/115 Titanium dioxide- or titanate type
		7/118	. . . Carbide, e.g. SiC type
		7/12	. . Overvoltage protection resistors {(series resistors structurally associated with spark gaps H01T 1/16)}
		7/123	. . . {Arrangements for improving potential distribution}
		7/126	. . . {Means for protecting against excessive pressure or for disconnecting in case of failure}
		7/13	. current responsive
			NOTE
			Groups H01C 7/02 - H01C 7/13 take precedence over groups H01C 7/18 - H01C 7/22 .
7/001	. {Mass resistors}		
7/003	. {Thick film resistors}		
7/005	. . {Polymer thick films}		
7/006	. {Thin film resistors}		
7/008	. {Thermistors (H01C 7/02 - H01C 7/06 take precedence)}	7/18	. comprising a plurality of layers stacked between terminals
7/02	. having positive temperature coefficient {(ceramics C04B)}	7/20	. the resistive layer or coating being tapered
7/021	. . {formed as one or more layers or coatings}	7/22	. Elongated resistive element being bent or curved, e.g. sinusoidal, helical
7/022	. . {mainly consisting of non-metallic substances (H01C 7/021 takes precedence)}	8/00	Non-adjustable resistors consisting of loose powdered or granular conducting, or powdered or granular semi-conducting material
7/023	. . . {containing oxides or oxidic compounds, e.g. ferrites}	8/02	. Cohereers or like imperfect resistors for detecting electromagnetic waves
7/025 {Perowskites, e.g. titanates}	8/04	. Overvoltage protection resistors; Arresters
7/026 {Vanadium oxides or oxidic compounds, e.g. VO _x }	10/00	Adjustable resistors
7/027	. . {consisting of conducting or semi-conducting material dispersed in a non-conductive organic material}	10/005	. {Surface mountable, e.g. chip trimmer potentiometer}
7/028	. . {consisting of organic substances}	10/02	. Liquid resistors
7/04	. having negative temperature coefficient {(thermometers using resistive elements G01K 7/16)}	10/025	. . {Electrochemical variable resistors (trimming resistors by electrolytic treatment H01C 17/2412 , H01C 17/262)}
7/041	. . {formed as one or more layers or coatings}	10/04	. with specified mathematical relationship between movement of resistor actuating means and value of resistance, other than direct proportional relationship
7/042	. . {mainly consisting of inorganic non-metallic substances (H01C 7/041 takes precedence)}	10/06	. adjustable by short-circuiting different amounts of the resistive element
	NOTE	10/08	. . with intervening conducting structure between the resistive element and the short-circuiting means, e.g. taps
	In groups H01C 7/043 - H01C 7/049 , in the absence of an indication to the contrary, classification is made in the last appropriate place	10/10	. adjustable by mechanical pressure or force
7/043 {Oxides or oxidic compounds}	10/103	. . {by using means responding to magnetic or electric fields, e.g. by addition of magnetisable or piezoelectric particles to the resistive material, or by an electromagnetic actuator}
7/044 {Zinc or cadmium oxide}		
7/045 {Perowskites, e.g. titanates}		
7/046 {Iron oxides or ferrites}		

10/106	. . {on resistive material dispersed in an elastic material (H01C 10/103 and H01C 10/12 take precedence; for electric switches H01H 1/029)}	13/00	Resistors not provided for elsewhere
10/12	. . by changing surface pressure between resistive masses or resistive and conductive masses, e.g. pile type	13/02	. Structural combinations of resistors (impedance networks per se H03H)
10/14	. adjustable by auxiliary driving means	17/00	Apparatus or processes specially adapted for manufacturing resistors (providing fillings for housings or enclosures H01C 1/02; reducing insulation surrounding a resistor to powder H01C 1/03; manufacture of thermally variable resistors H01C 7/02, H01C 7/04)
10/16	. including plural resistive elements	17/003	. {using lithography, e.g. photolithography (lithographic compositions and processing in general G03F)}
10/18	. . including coarse and fine resistive elements	17/006	. {adapted for manufacturing resistor chips}
10/20	. . Contact structure or movable resistive elements being ganged	17/02	. adapted for manufacturing resistors with envelope or housing
10/22	. resistive element dimensions changing gradually in one direction, e.g. tapered resistive element (H01C 10/04 takes precedence)	17/04	. adapted for winding the resistive element
10/23	. resistive element dimensions changing in a series of discrete, progressive steps	17/06	. adapted for coating resistive material on a base
10/24	. the contact moving along turns of a helical resistive element, or vica versa	17/065	. . by thick film techniques, e.g. serigraphy
10/26	. resistive element moving (H01C 10/16 , H01C 10/24 take precedence)	17/06506	. . . {Precursor compositions therefor, e.g. pastes, inks, glass frits}
	NOTE	17/06513 {characterised by the resistive component}
	Groups H01C 10/02 - H01C 10/26 take precedence over groups H01C 10/28 - H01C 10/50 .	17/0652 {containing carbon or carbides}
10/28	. the contact rocking or rolling along resistive element or taps	17/06526 {composed of metals}
10/30	. the contact sliding along resistive element	17/06533 {composed of oxides}
10/301	. . {consisting of a wire wound resistor}	17/0654 {Oxides of the platinum group}
10/303	. . . {the resistor being coated, e.g. lubricated, conductive plastic coated, i.e. hybrid potentiometer}	17/06546 {Oxides of zinc or cadmium}
10/305	. . {consisting of a thick film}	17/06553 {composed of a combination of metals and oxides}
10/306	. . . {Polymer thick film, i.e. PTF}	17/0656 {composed of silicides (H01C 17/0652 takes precedence)}
10/308	. . {consisting of a thin film}	17/06566 {composed of borides (H01C 17/0652 takes precedence)}
10/32	. . the contact moving in an arcuate path	17/06573 {characterised by the permanent binder}
10/34	. . . the contact or the associated conducting structure riding on collector formed as a ring or portion thereof	17/0658 {composed of inorganic material}
10/345 {the collector and resistive track being situated in 2 parallel planes}	17/06586 {composed of organic material}
10/36	. . . structurally combined with switching arrangements	17/06593 {characterised by the temporary binder}
10/363 {by axial movement of the spindle, e.g. pull-push switch (H01C 10/366 takes precedence)}	17/07	. . by resistor foil bonding, e.g. cladding
10/366 {using an electromagnetic actuator}	17/075	. . by thin film techniques (H01C 17/20 takes precedence)}
10/38	. . the contact moving along a straight path	17/08	. . . by vapour deposition
10/40	. . . screw operated	17/10	. . . by flame spraying
10/42 the contact bridging and sliding along resistive element and parallel conducting bar or collector	17/12	. . . by sputtering
10/44	. . . the contact bridging and sliding along resistive element and parallel conducting bar or collector (H01C 10/42 takes precedence)	17/14	. . . by chemical deposition
10/46	. Arrangements of fixed resistors with intervening connectors, e.g. taps (H01C 10/28 , H01C 10/30 take precedence)	17/16 using electric current
10/48	. . including contact movable in an arcuate path	17/18 without using electric current
10/50	. structurally combined with switching arrangements (H01C 10/36 takes precedence)	17/20	. . by pyrolytic processes
11/00	Non-adjustable liquid resistors	17/22	. adapted for trimming
		17/23	. . by opening or closing resistor geometric tracks of predetermined resistive values, {e.g. snapistors }
		17/232	. . Adjusting the temperature coefficient; Adjusting value of resistance by adjusting temperature coefficient of resistance
		17/235	. . Initial adjustment of potentiometer parts for calibration
		17/24	. . by removing or adding resistive material (H01C 17/23 , H01C 17/232 , H01C 17/235 take precedence)
		17/2404	. . . {by charged particle impact, e.g. by electron or ion beam milling, sputtering, plasma etching}
		17/2408	. . . {by pulsed voltage erosion, e.g. spark erosion}
		17/2412	. . . {by electrolytic treatment, e.g. electroplating (for anodic oxydation H01C 17/262)}
		17/2416	. . . {by chemical etching}

H01C

- 17/242 . . . by laser {(trimming by laser in general [B23K 26/351](#))}
- 17/245 . . . by mechanical means, e.g. sand blasting, cutting, ultrasonic treatment
- 17/26 . . by converting resistive material
- 17/262 . . . {by electrolytic treatment, e.g. anodic oxydation}
- 17/265 . . . {by chemical or thermal treatment, e.g. oxydation, reduction, annealing ([etching H01C 17/2416](#))}
- 17/267 {by passage of voltage pulses or electric current}
- 17/28 . . adapted for applying terminals
- 17/281 . . {by thick film techniques}
- 17/283 . . . {Precursor compositions therefor, e.g. pastes, inks, glass frits}
- 17/285 {applied to zinc or cadmium oxide resistors}
- 17/286 {applied to TiO₂ or titanate resistors}
- 17/288 . . {by thin film techniques}
- 17/30 . . adapted for baking